



BCV61

NPN general-purpose double transistors

Rev. 04 — 18 December 2009

Product data sheet

1. Product profile

1.1 General description

NPN general-purpose double transistors in a small SOT143B Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	Package		PNP complement
	Nexperia	JEITA	
BCV61	SOT143B	-	BCV62
BCV61A			BCV62A
BCV61B			BCV62B
BCV61C			BCV62C

1.2 Features

- Low current (max. 100 mA)
- Low voltage (max. 30 V)
- Matched pairs

1.3 Applications

- Applications with working point independent of temperature
- Current mirrors

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	collector TR2; base TR1 and TR2		
2	collector TR1		
3	emitter TR1		
4	emitter TR2		

006aaa842

nexperia

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BCV61	-	plastic surface-mounted package; 4 leads	SOT143B
BCV61A			
BCV61B			
BCV61C			

4. Marking

Table 4. Marking codes

Type number	Marking code ^[1]
BCV61	1M*
BCV61A	1J*
BCV61B	1K*
BCV61C	1L*

[1] * = -: made in Hong Kong

* = p: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transistor					
V _{CBO}	collector-base voltage	open emitter	-	30	V
V _{CEO}	collector-emitter voltage	open base	-	30	V
V _{EBS}	emitter-base voltage	V _{CE} = 0 V	-	6	V
I _C	collector current		-	100	mA
I _{CM}	peak collector current		-	200	mA
I _{BM}	peak base current		-	200	mA
Per device					
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	mW
T _j	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB).

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	500 K/W

[1] Device mounted on an FR4 PCB.

7. Characteristics

Table 7. Characteristics

$T_j = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
Transistor TR1							
I_{CBO}	collector-base cut-off current	$V_{CB} = 30\text{ V}; I_E = 0\text{ A}$	-	-	15	nA	
		$V_{CB} = 30\text{ V}; I_E = 0\text{ A}; T_j = 150^\circ\text{C}$	-	-	5	μA	
I_{EBO}	emitter-base cut-off current	$V_{EB} = 5\text{ V}; I_C = 0\text{ A}$	-	-	100	nA	
h_{FE}	DC current gain	$V_{CE} = 5\text{ V}; I_C = 100\text{ }\mu\text{A}$	100	-	-		
		$V_{CE} = 5\text{ V}; I_C = 2\text{ mA}$	110	-	800		
V_{CEsat}	collector-emitter saturation voltage	$I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$	-	90	250	mV	
		$I_C = 100\text{ mA}; I_B = 5\text{ mA}$	-	200	600	mV	
V_{BEsat}	base-emitter saturation voltage	$I_C = 10\text{ mA}; I_B = 0.5\text{ mA}$	[1]	-	700	-	mV
		$I_C = 100\text{ mA}; I_B = 5\text{ mA}$	[1]	-	900	-	mV
V_{BE}	base-emitter voltage	$I_C = 2\text{ mA}; V_{CE} = 5\text{ V}$	[2]	580	660	700	mV
		$I_C = 10\text{ mA}; V_{CE} = 5\text{ V}$	[2]	-	-	770	mV
f_T	transition frequency	$V_{CE} = 5\text{ V}; I_C = 10\text{ mA}; f = 100\text{ MHz}$	100	-	-	MHz	
C_c	collector capacitance	$V_{CB} = 10\text{ V}; I_E = i_e = 0\text{ A}; f = 1\text{ MHz}$	-	2.5	-	pF	
NF	noise figure	$V_{CE} = 5\text{ V}; I_C = 200\text{ }\mu\text{A}; R_S = 2\text{ k}\Omega; f = 1\text{ kHz}; B = 200\text{ Hz}$	-	-	10	dB	

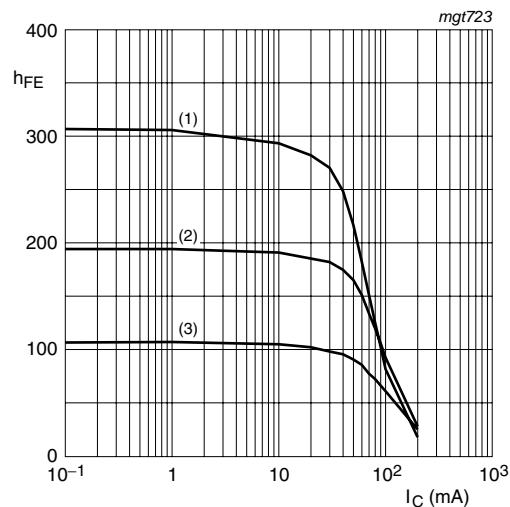
Table 7. Characteristics ...continued
 $T_j = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Transistor TR2						
V_{EBS}	emitter-base voltage	$V_{CB} = 0 \text{ V};$ $I_E = -250 \text{ mA}$	-	-	-1.8	V
		$V_{CB} = 0 \text{ V};$ $I_E = -10 \mu\text{A}$	-400	-	-	mV
h_{FE}	DC current gain	$V_{CE} = 5 \text{ V};$ $I_C = 2 \text{ mA}$				
	BCV61		110	-	800	
	BCV61A		110	-	220	
	BCV61B		200	-	450	
	BCV61C		420	-	800	
Transistors TR1 and TR2						
I_{C1}/I_{E2}	current matching	$I_{E2} = -0.5 \text{ mA};$ $V_{CE1} = 5 \text{ V}$				
		$T_{amb} \leq 25^\circ\text{C}$	0.7	-	1.3	
		$T_{amb} \leq 150^\circ\text{C}$	0.7	-	1.3	
I_{E2}	emitter current 2	$V_{CE1} = 5 \text{ V}$	[3]	-	-5	mA

[1] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.

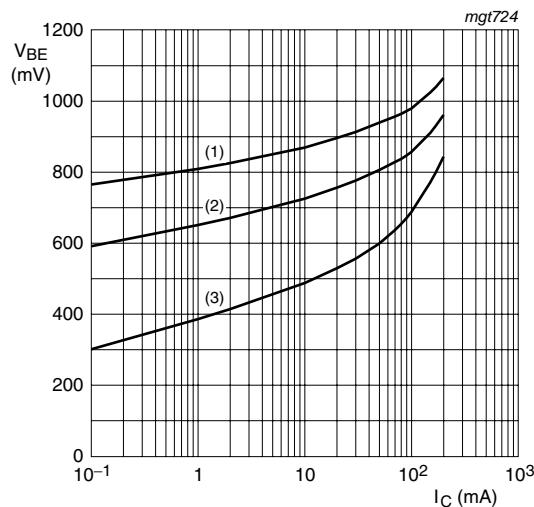
[2] V_{BE} decreases by about 2 mV/K with increasing temperature.

[3] Device, without emitter resistors, mounted on an FR4 PCB.



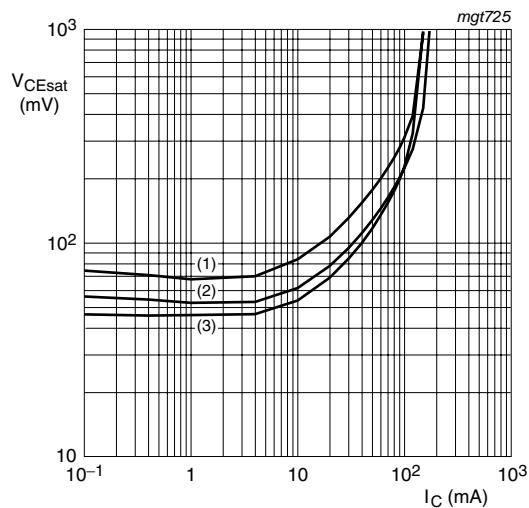
$V_{CE} = 5$ V
(1) $T_{amb} = 150$ °C
(2) $T_{amb} = 25$ °C
(3) $T_{amb} = -55$ °C

Fig 1. BCV61A: DC current gain as a function of collector current; typical values



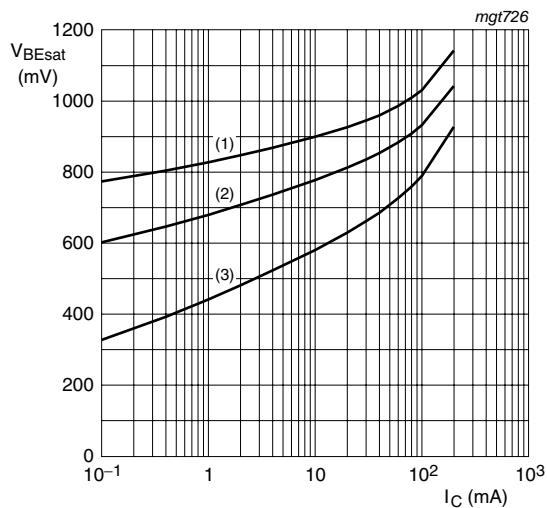
$V_{CE} = 5$ V
(1) $T_{amb} = -55$ °C
(2) $T_{amb} = 25$ °C
(3) $T_{amb} = 150$ °C

Fig 2. BCV61A: Base-emitter voltage as a function of collector current; typical values



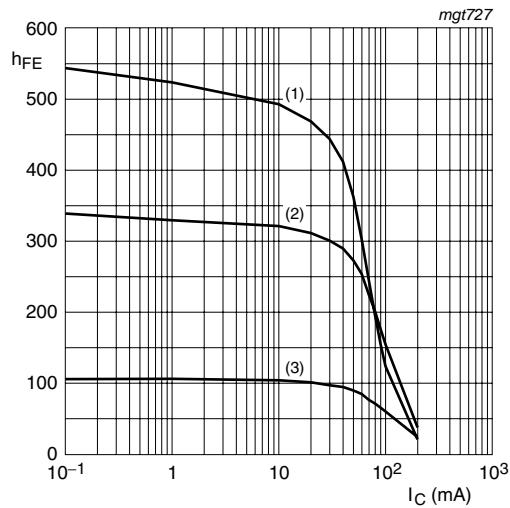
$I_C/I_B = 20$
(1) $T_{amb} = 150$ °C
(2) $T_{amb} = 25$ °C
(3) $T_{amb} = -55$ °C

Fig 3. BCV61A: Collector-emitter saturation voltage as a function of collector current; typical values



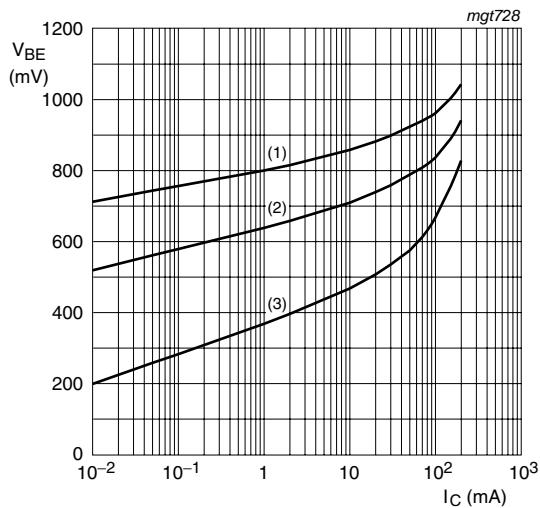
$I_C/I_B = 10$
(1) $T_{amb} = -55$ °C
(2) $T_{amb} = 25$ °C
(3) $T_{amb} = 150$ °C

Fig 4. BCV61A: Base-emitter saturation voltage as a function of collector current; typical values



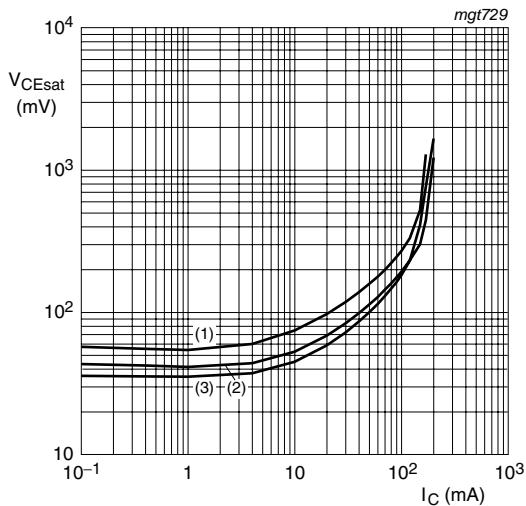
$V_{CE} = 5 \text{ V}$
(1) $T_{amb} = 150 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = -55 \text{ }^{\circ}\text{C}$

Fig 5. BCV61B: DC current gain as a function of collector current; typical values



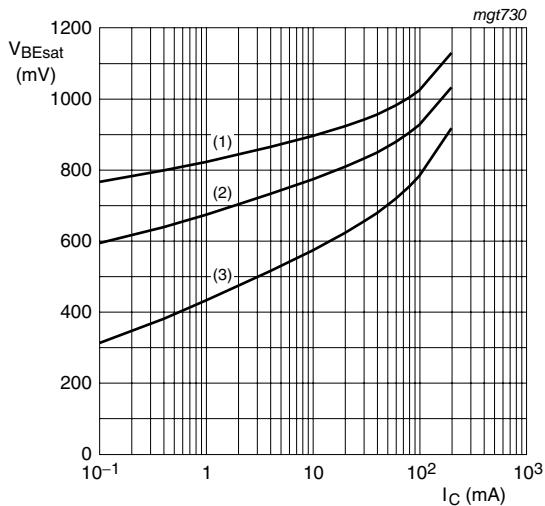
$V_{CE} = 5 \text{ V}$
(1) $T_{amb} = -55 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = 150 \text{ }^{\circ}\text{C}$

Fig 6. BCV61B: Base-emitter voltage as a function of collector current; typical values



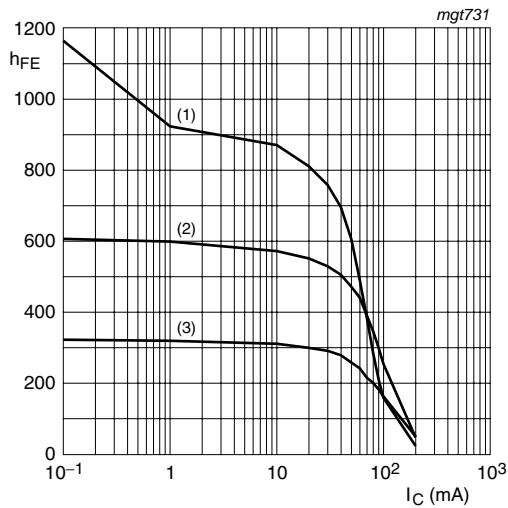
$I_C/I_B = 20$
(1) $T_{amb} = 150 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = -55 \text{ }^{\circ}\text{C}$

Fig 7. BCV61B: Collector-emitter saturation voltage as a function of collector current; typical values



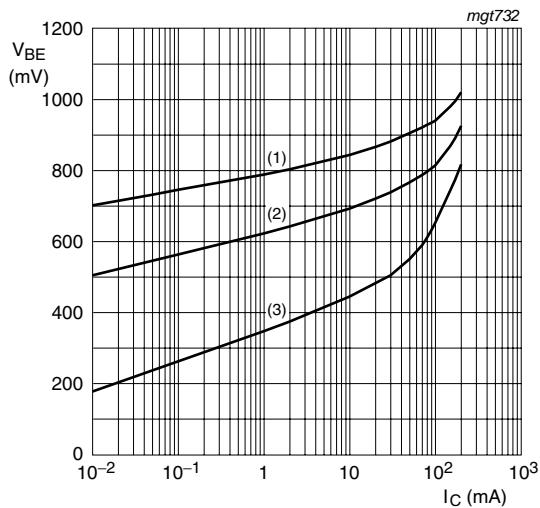
$I_C/I_B = 10$
(1) $T_{amb} = -55 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = 150 \text{ }^{\circ}\text{C}$

Fig 8. BCV61B: Base-emitter saturation voltage as a function of collector current; typical values



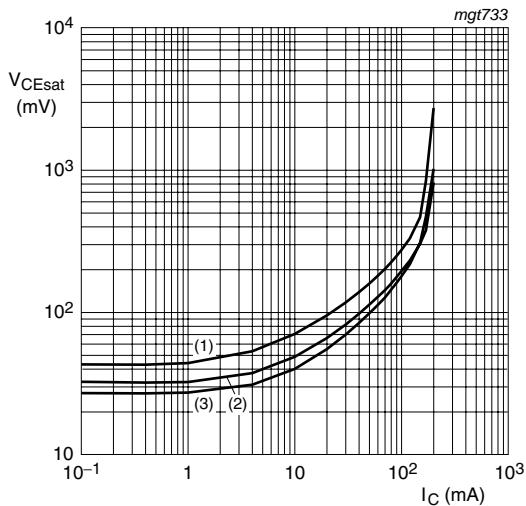
$V_{CE} = 5 \text{ V}$
(1) $T_{amb} = 150 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = -55 \text{ }^{\circ}\text{C}$

Fig 9. BCV61C: DC current gain as a function of collector current; typical values



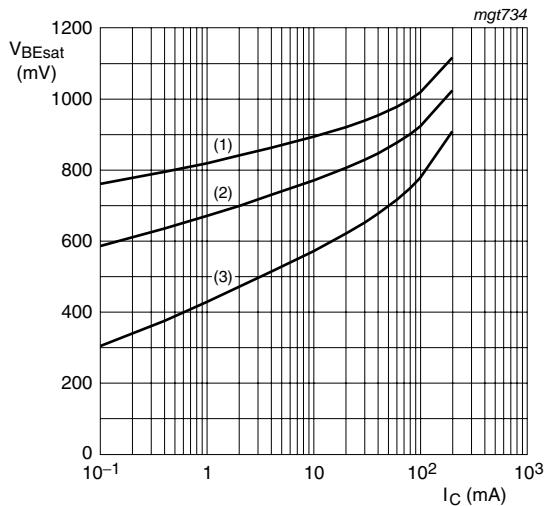
$V_{CE} = 5 \text{ V}$
(1) $T_{amb} = -55 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = 150 \text{ }^{\circ}\text{C}$

Fig 10. BCV61C: Base-emitter voltage as a function of collector current; typical values



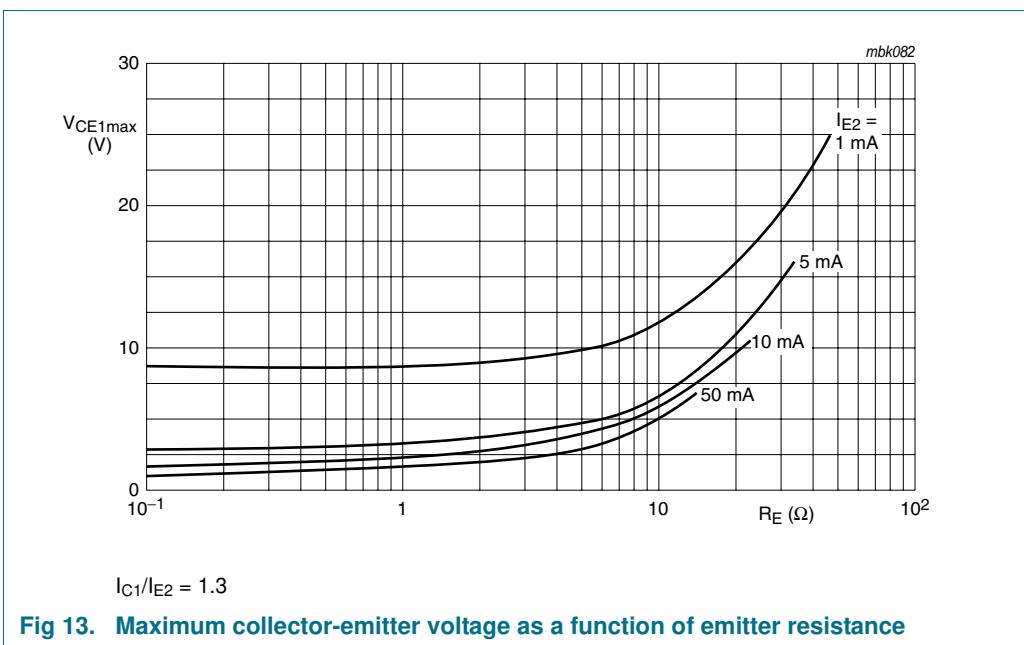
$I_C/I_B = 20$
(1) $T_{amb} = 150 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = -55 \text{ }^{\circ}\text{C}$

Fig 11. BCV61C: Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 10$
(1) $T_{amb} = -55 \text{ }^{\circ}\text{C}$
(2) $T_{amb} = 25 \text{ }^{\circ}\text{C}$
(3) $T_{amb} = 150 \text{ }^{\circ}\text{C}$

Fig 12. BCV61C: Base-emitter saturation voltage as a function of collector current; typical values



8. Test information

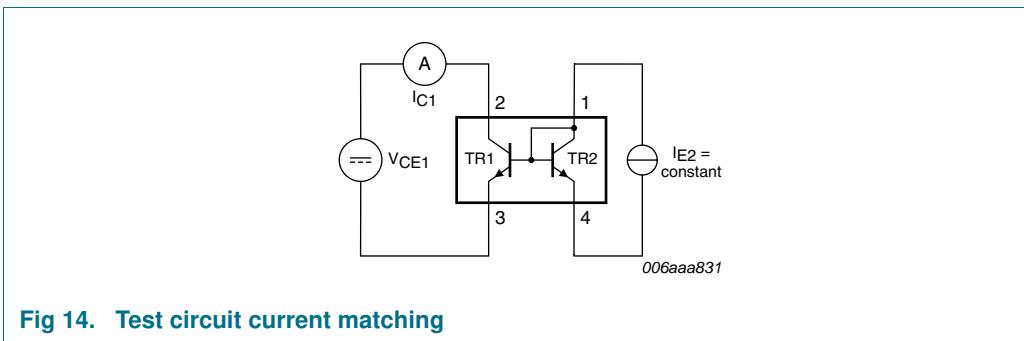


Fig 14. Test circuit current matching

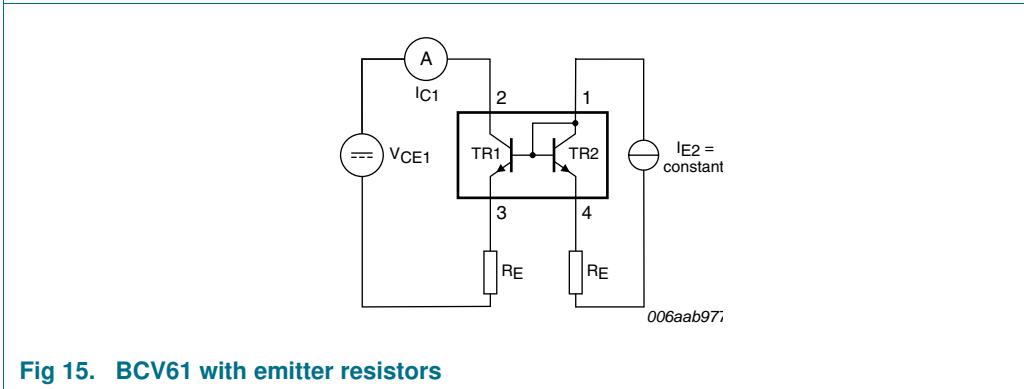


Fig 15. BCV61 with emitter resistors

9. Package outline

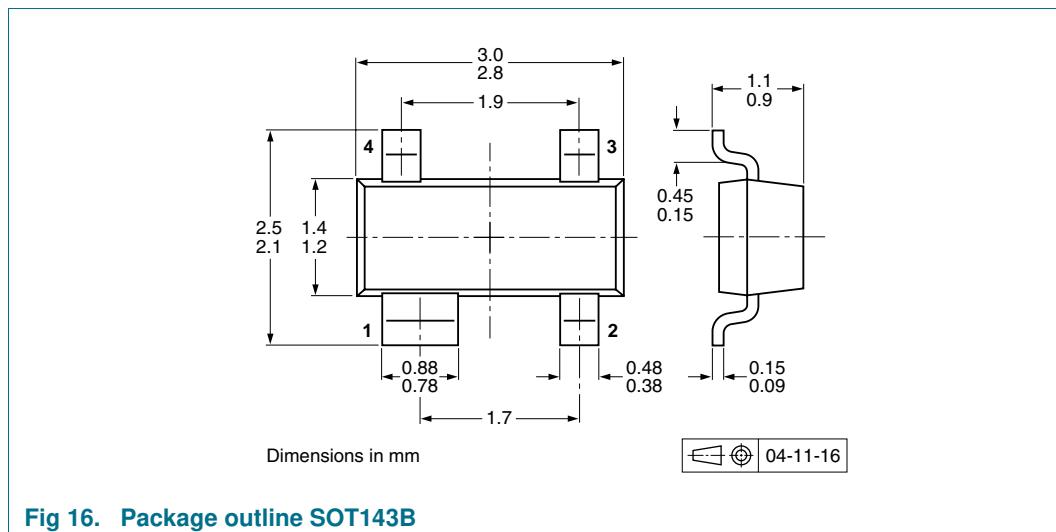


Fig 16. Package outline SOT143B

10. Packing information

Please refer to packing information on www.nexperia.com.

11. Soldering

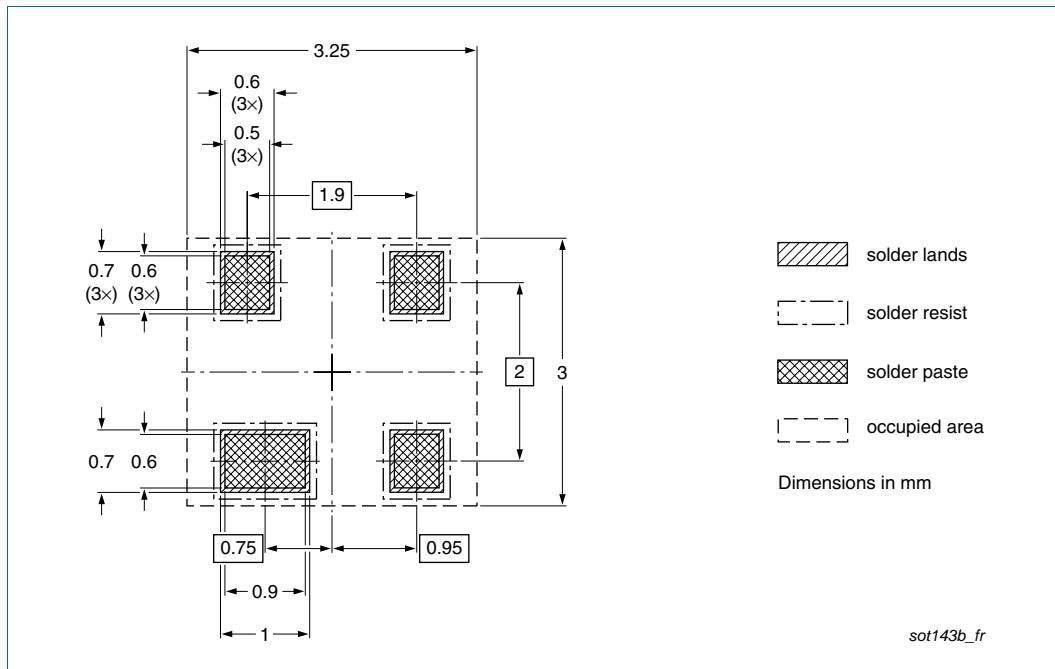


Fig 17. Reflow soldering footprint SOT143B

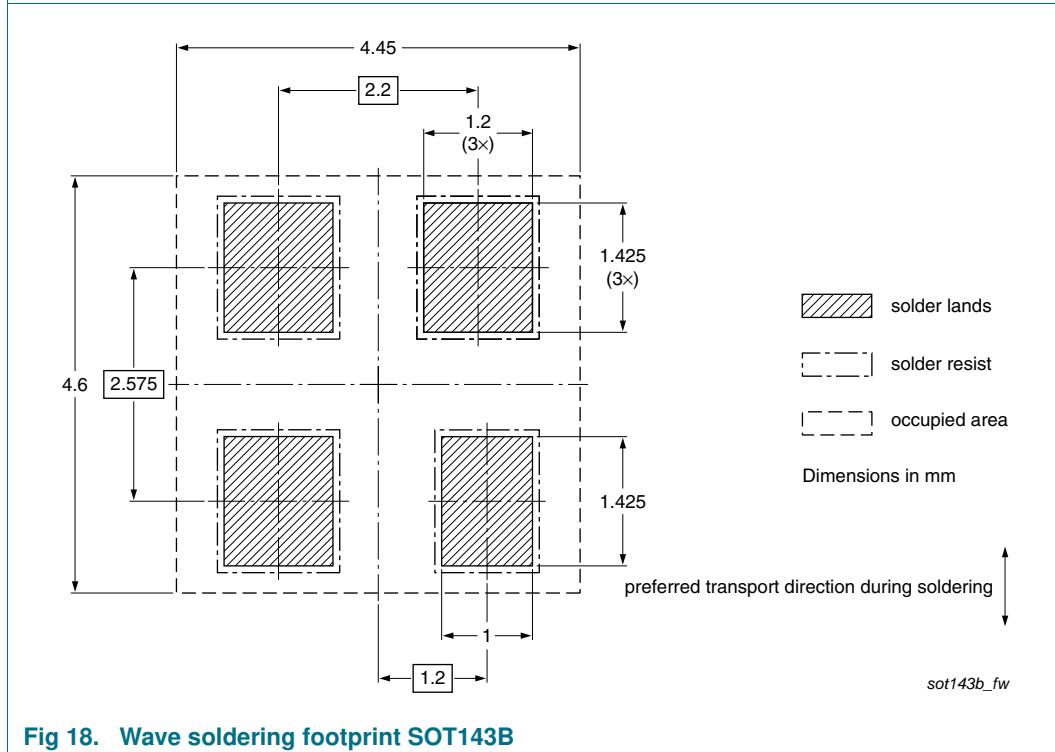


Fig 18. Wave soldering footprint SOT143B

12. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BCV61_4	20091218	Product data sheet	-	BCV61_3
Modifications:	<ul style="list-style-type: none">The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.Legal texts have been adapted to the new company name where appropriate.Section 3 “Ordering information”: addedSection 4 “Marking”: updatedFigure 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 and 12: addedSection 8 “Test information”: addedFigure 16: superseded by minimized package outline drawingSection 10 “Packing information”: addedSection 11 “Soldering”: addedSection 13 “Legal information”: updated			
BCV61_3	19990408	Product specification	-	BCV61_CNV_2
BCV61_CNV_2	19970616	Product specification	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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